HEF4051B

8-channel analog multiplexer/demultiplexer Rev. 11 — 11 September 2014

Product data sheet

1. **General description**

The HEF4051B is an 8-channel analog multiplexer/demultiplexer with three address inputs (S1 to S3), an active LOW enable input (E), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). The device contains eight bidirectional analog switches, each with one side connected to an independent input/output (Y0 to Y7) and the other side connected to a common input/output (Z). With E LOW, one of the eight switches is selected (low-impedance ON-state) by S1 to S3. With E HIGH, all switches are in the high-impedance OFF-state, independent of S1 to S3. If break before make is needed, then it is necessary to use the enable input.

 V_{DD} and V_{SS} are the supply voltage connections for the digital control inputs (S1 to S3, and E). The V_{DD} to V_{SS} range is 3 V to 15 V. The analog inputs/outputs (Y0 to Y7, and Z) can swing between V_{DD} as a positive limit and V_{EE} as a negative limit. $V_{DD} - V_{EE}$ may not exceed 15 V. Unused inputs must be connected to V_{DD}, V_{SS}, or another input. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to V_{SS} (typically ground). V_{EE} and V_{SS} are the supply voltage connections for the switches.

2. Features and benefits

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B

Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



8-channel analog multiplexer/demultiplexer

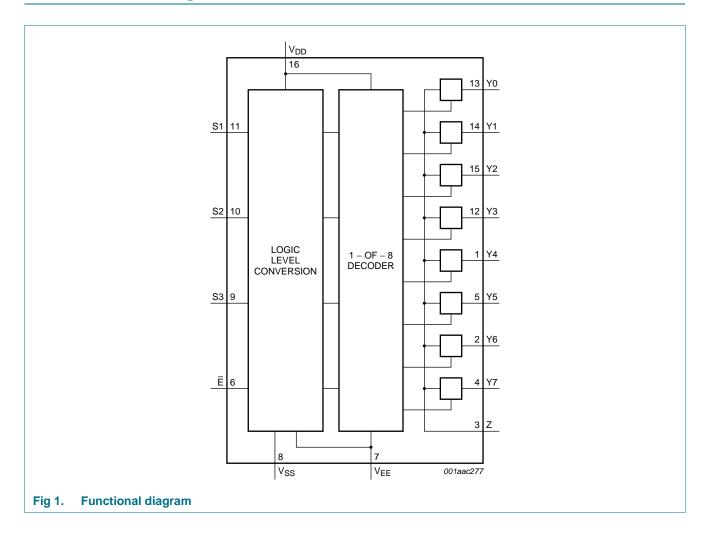
4. Ordering information

Table 1. Ordering information

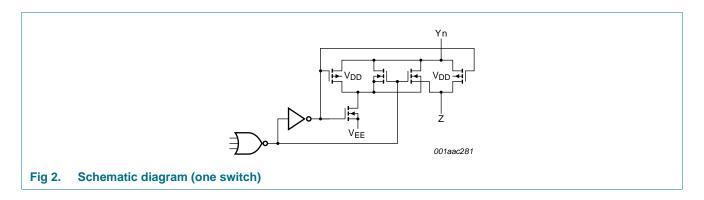
All types operate from -40~% to +125~%.

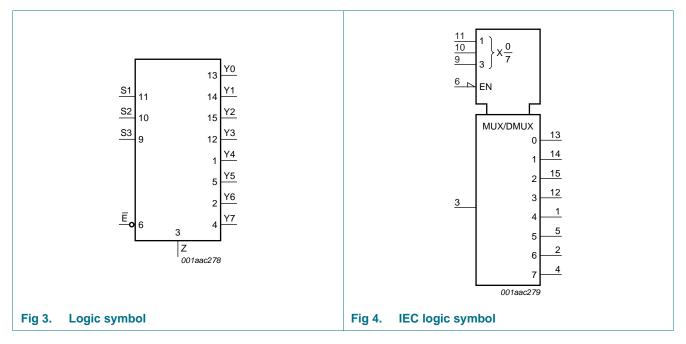
Type number	Package								
	Name	Description	Version						
HEF4051BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
HEF4051BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						
HEF4051BTS	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1						
HEF4051BTT	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						

5. Functional diagram

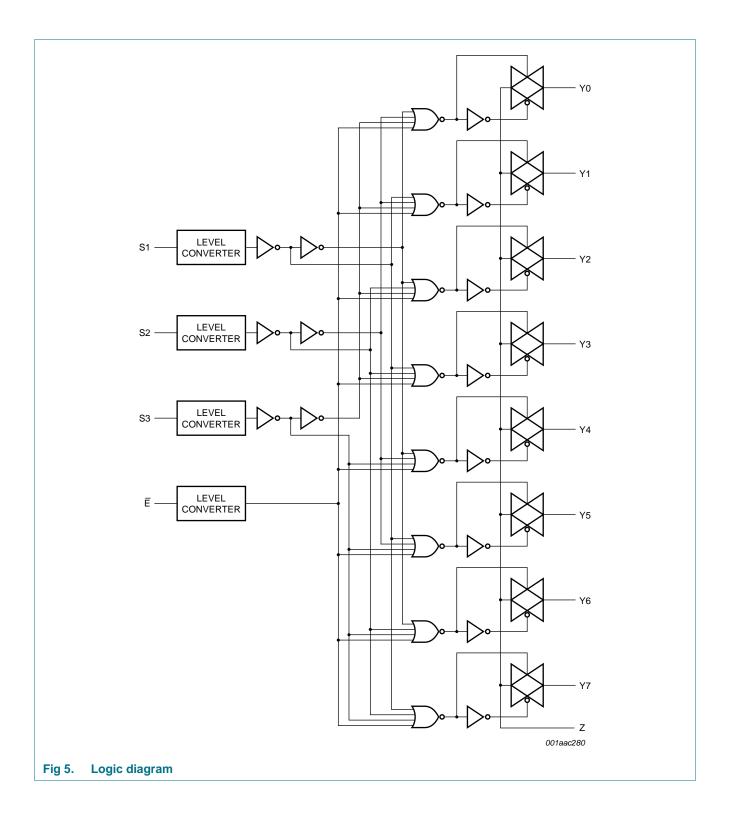


8-channel analog multiplexer/demultiplexer





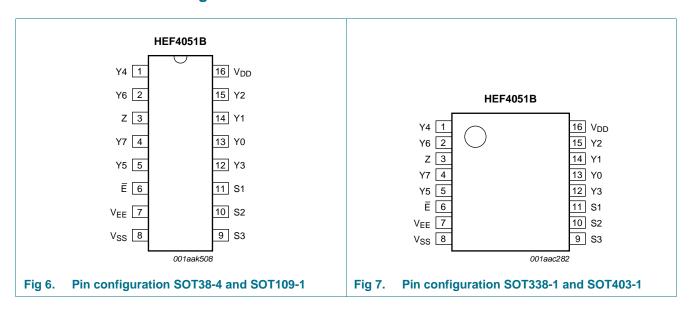
8-channel analog multiplexer/demultiplexer



8-channel analog multiplexer/demultiplexer

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Ē	6	enable input (active LOW)
V _{EE}	7	supply voltage
V_{SS}	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	13, 14, 15, 12, 1, 5, 2, 4	independent input or output
Z	3	common output or input
V_{DD}	16	supply voltage

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7. Functional description

7.1 Function table

Table 3. Function table [1]

Input				Channel ON
E	S3	S2	S1	
L	L	L	L	Y0 to Z
L	L	L	Н	Y1 to Z
L	L	Н	L	Y2 to Z
L	L	Н	Н	Y3 to Z
L	Н	L	L	Y4 to Z
L	Н	L	Н	Y5 to Z
L	Н	Н	L	Y6 to Z
L	Н	Н	Н	Y7 to Z
Н	X	Х	X	switches off

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V (ground)}$.

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DD}	supply voltage			-0.5	+18	V
V _{EE}	supply voltage	referenced to V _{DD}	[1]	-18	+0.5	V
I _{IK}	input clamping current	pins Sn and \overline{E} ; V _I < -0.5 V or V _I > V _{DD} + 0.5 V		-	±10	mA
VI	input voltage			-0.5	V _{DD} + 0.5	V
I _{I/O}	input/output current			-	±10	mA
I _{DD}	supply current			-	50	mA
T _{stg}	storage temperature			-65	+150	°C
T _{amb}	ambient temperature			-40	+125	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]			
		DIP16 package		-	750	mW
		SO16 package		-	500	mW
		SSOP16 package		-	500	mW
		TSSOP16 package		-	500	mW
Р	power dissipation	per output		-	100	mW

^[1] To avoid drawing V_{DD} current out of terminal Z, when switch current flows into terminals Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{DD} current will flow out of terminals Y, and in this case there is no limit for the voltage drop across the switch, but the voltages at Y and Z may not exceed V_{DD} or V_{EE}.

^[2] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.
For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage	see Figure 8	3	-	15	V
V _I	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall	$V_{DD} = 5 \text{ V}$	-	-	3.75	μs/V
	rate	V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

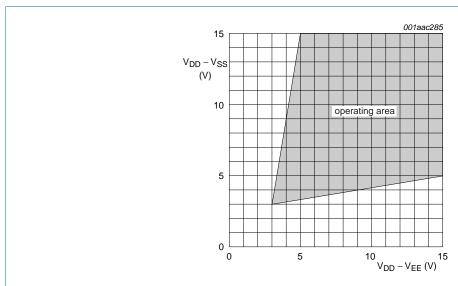


Fig 8. Operating area as a function of the supply voltages

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = V_{EE} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	ol Parameter Conditions		tions V _{DD} T		T _{amb} =	$t_{amb} = -40 ^{\circ}\text{C}$ $T_{amb} = 25 ^{\circ}\text{C}$		T _{amb} = 85 °C		T _{amb} =	125 °C	Unit	
					Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	I _O < 1 μA	5 V		3.5	-	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V		7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V		11.0	-	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	101	5 V		-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V		-	3.0	-	3.0	-	3.0	-	3.0	V
		15 V		-	4.0	-	4.0	-	4.0	-	4.0	V	
l _l	input leakage current		15 V		-	±0.1	-	±0.1	-	±1.0	-	±1.0	μΑ

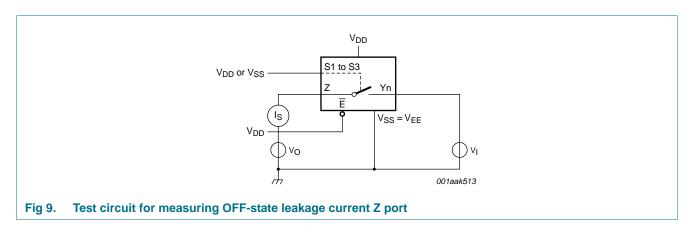
8-channel analog multiplexer/demultiplexer

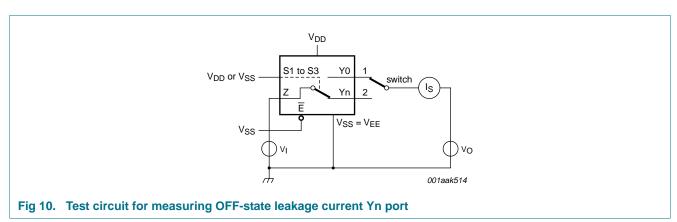
 Table 6.
 Static characteristics ...continued

 $V_{SS} = V_{EE} = 0 \text{ V}; V_I = V_{SS} \text{ or } V_{DD} \text{ unless otherwise specified.}$

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	T _{amb} = -40 °C		25 °C	T _{amb} =	85 °C	T _{amb} =	125 °C	Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
I _{S(OFF)}	OFF-state leakage current	Z port; all channels OFF; see <u>Figure 9</u>	15 V	-	-	-	1000	-	-	-	-	nA
		Y port; per channel; see Figure 10	15 V	-	-	-	200	-	-	-	-	nA
I _{DD}	supply current	I _O = 0 A	5 V	-	5	-	5	-	150	-	150	μΑ
			10 V	-	10	-	10	-	300	-	300	μΑ
			15 V	-	20	-	20	-	600	-	600	μΑ
Cı	input capacitance	Sn, E inputs	-	-	-	-	7.5	-	-	-	-	pF

10.1 Test circuits





8-channel analog multiplexer/demultiplexer

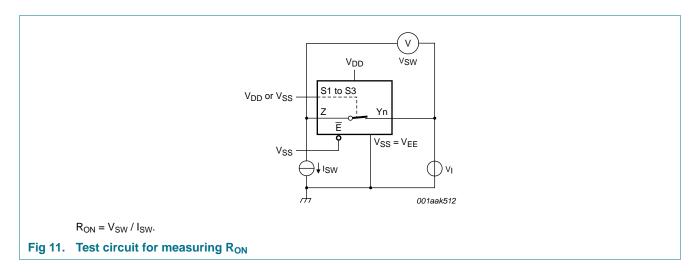
10.2 ON resistance

Table 7. ON resistance

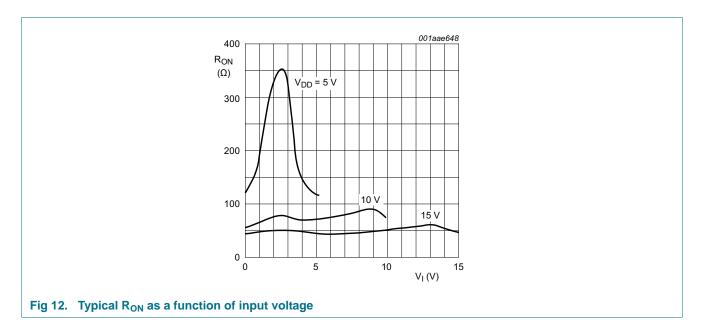
 $T_{amb} = 25$ °C; $I_{SW} = 200~\mu A$; $V_{SS} = V_{EE} = 0~V$.

Symbol	Parameter	Conditions	$V_{DD} - V_{EE}$	Тур	Max	Unit
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 V \text{ to } V_{DD} - V_{EE};$	5 V	350	2500	Ω
		see Figure 11 and Figure 12	10 V	80	245	Ω
			15 V	60	2500 Ω 245 Ω 175 Ω 340 Ω 160 Ω 115 Ω 200 Ω 155 Ω - Ω	Ω
R _{ON(rail)}	ON resistance (rail)	V _I = 0 V; see <u>Figure 11</u> and <u>Figure 12</u>	5 V	115	340	Ω
			160	Ω		
			15 V	40	115	Ω
		$V_I = V_{DD} - V_{EE};$	5 V	120	365	Ω
		see Figure 11 and Figure 12	10 V	65	200	Ω
			15 V	50	155	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = 0 \text{ V to } V_{DD} - V_{EE}$; see Figure 11	5 V	25	-	Ω
	between channels		10 V	10	-	Ω
			15 V	5	-	Ω

10.2.1 ON resistance waveform and test circuit



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11. Dynamic characteristics

Table 8. Dynamic characteristics

 $T_{amb} = 25$ °C; $V_{SS} = V_{EE} = 0$ V; for test circuit see <u>Figure 16</u>.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
t _{PHL}	HIGH to LOW propagation delay	Yn, Z to Z, Yn; see Figure 13	5 V	15	30	ns
				ns		
			15 V	5	30 10 10 300 120 90 30 10 10 300 130 90 240 180 170 280 110	ns
		Sn to Yn, Z; see Figure 14	5 V	150	300	ns
			10 V	60	120	ns
			15 V	45	10 10 300 120 90 30 10 10 300 130 90 240 180 170 280 110 80 290	ns
t _{PLH}	LOW to HIGH propagation delay	Yn, Z to Z, Yn; see Figure 13	5 V	15	30	ns
			10 V	5	10	ns
			15 V	5	10	ns
		Sn to Yn, Z; see Figure 14	5 V	150	300	ns
			10 V	65	130	ns
			15 V	45	10 300 120 90 30 10 10 300 130 90 240 180 170 280 110 80 290	ns
t _{PHZ}	HIGH to OFF-state	E to Yn, Z; see Figure 15	15 V 5 10 5 V 150 300 10 V 60 120 15 V 45 90 5 V 15 30 10 V 5 10 15 V 5 10 5 V 150 300 10 V 65 130 15 V 45 90 5 V 120 240 10 V 90 180 15 V 85 170 5 V 140 280 10 V 55 110 15 V 40 80 5 V 145 290	ns		
	propagation delay		10 V	90	180	ns
			15 V	85	170	ns
t _{PZH}	OFF-state to HIGH	E to Yn, Z; see Figure 15	5 V	140	280	ns
	propagation delay		10 V	55	110	ns
			15 V	40	80	ns
t _{PLZ}	LOW to OFF-state	E to Yn, Z; see Figure 15	5 V	145	290	ns
	propagation delay		10 V	120	240	ns
			15 V	115	230	ns

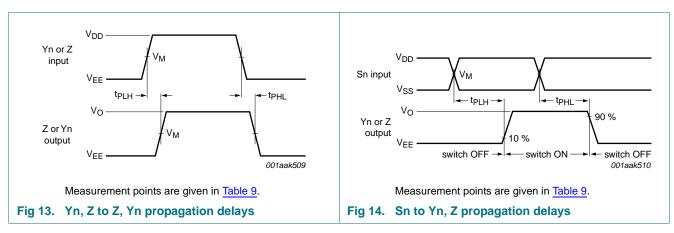
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 Table 8.
 Dynamic characteristics ...continued

 $T_{amb} = 25$ °C; $V_{SS} = V_{EE} = 0$ V; for test circuit see <u>Figure 16</u>.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
t_{PZL}		E to Yn, Z; see Figure 15	5 V	140	280	ns
	propagation delay		10 V	55	110	ns
			15 V	40	80	ns

11.1 Waveforms and test circuit



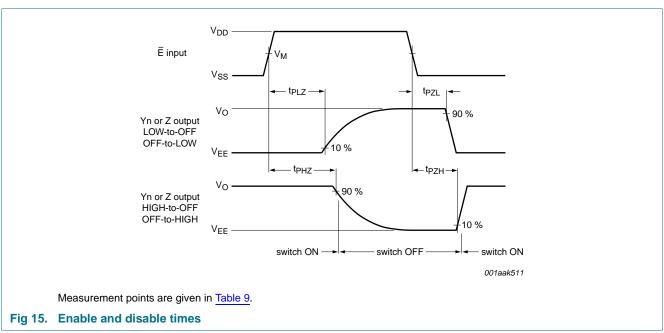


Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}

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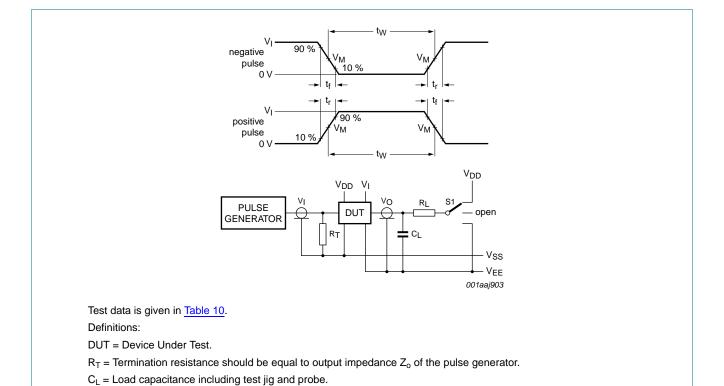


Fig 16. Test circuit for measuring switching times

R_L = Load resistance.

Table 10. Test data

Input _			Load		S1 position					
Yn, Z	Sn and E	t _r , t _f	V _M	CL	R_L	t _{PHL} [1]	t _{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}	other
V_{DD} or V_{EE}	V_{DD} or V_{SS}	≤ 20 ns	0.5V _{DD}	50 pF	10 kΩ	V_{DD} or V_{EE}	V _{EE}	V _{EE}	V_{DD}	V _{EE}

[1] For Yn to Z or Z to Yn propagation delays use V_{EE} . For Sn to Yn or Z propagation delays use V_{DD} .

8-channel analog multiplexer/demultiplexer

11.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

 $V_{SS} = V_{EE} = 0$ V; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	V_{DD}		Тур	Max	Unit
THD	total harmonic distortion	see Figure 17; $R_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$;	5 V	[1]	0.25	-	%
		channel ON; $V_I = 0.5V_{DD}$ (p-p);	10 V	[1]	0.04	-	%
	$f_i = 1 \text{ kHz}$	II = I KIIZ	15 V	[1]	0.04	-	%
f _(-3dB)	-3 dB frequency response	see Figure 18; $R_L = 1 \text{ k}\Omega$; $C_L = 5 \text{ pF}$;	5 V	[1]	13	-	MHz
		channel ON; $V_I = 0.5V_{DD}$ (p-p)	10 V	[1]	40	-	MHz
			15 V	[1]	70	-	MHz
α_{iso}	isolation (OFF-state)	see Figure 19; f_i = 1 MHz; R_L = 1 k Ω ; C_L = 5 pF; channel OFF; V_I = 0.5 V_{DD} (p-p)	10 V	[1]	-50	-	dB
V _{ct}	crosstalk voltage	digital inputs to switch; see Figure 20; $\underline{R}_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$; \overline{E} or $Sn = V_{DD}$ (square-wave)	10 V		50	-	mV
Xtalk	crosstalk	between switches; see Figure 21; $f_i = 1$ MHz; $R_L = 1$ k Ω ; $V_I = 0.5V_{DD}$ (p-p)	10 V	[1]	-50	-	dB

^[1] f_i is biased at 0.5 V_{DD} ; $V_I = 0.5 V_{DD}$ (p-p).

Table 12. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown; $V_{EE} = V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	V_{DD}	Typical formula for P _D (μW)	where:
P_D	dynamic power	5 V	$P_D = 1000 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f_i = input frequency in MHz;
	dissipation	10 V	$P_D = 5500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	fo = output frequency in MHz;
		15 V	$P_D = 15000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	C _L = output load capacitance in pF;
				V_{DD} = supply voltage in V;
				$\Sigma(C_L \times f_o)$ = sum of the outputs.

11.2.1 Test circuits

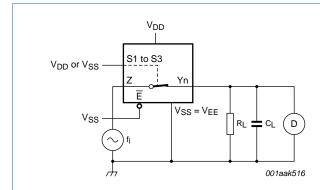


Fig 17. Test circuit for measuring total harmonic distortion

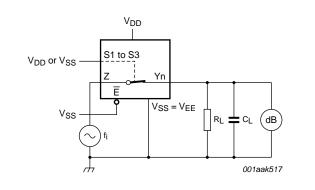
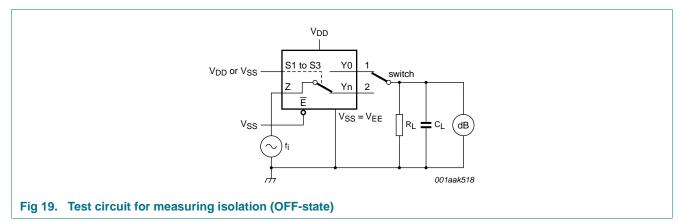


Fig 18. Test circuit for measuring frequency response

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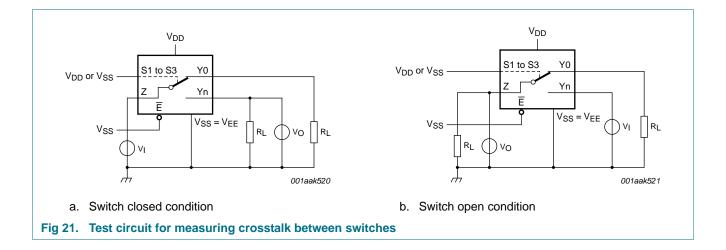
a. Test circuit

| O.5V_{DD} | V_{DD} |

Fig 20. Test circuit for measuring crosstalk voltage between digital inputs and switch

b. Input and output pulse definitions

8-channel analog multiplexer/demultiplexer

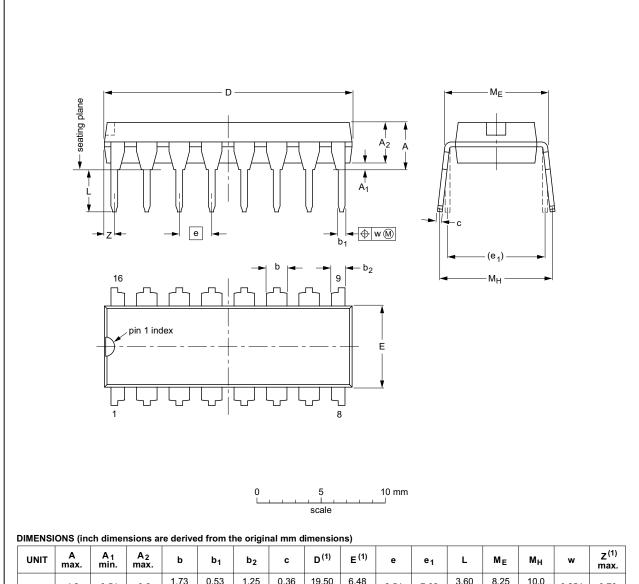


8-channel analog multiplexer/demultiplexer

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					95-01-14 03-02-13

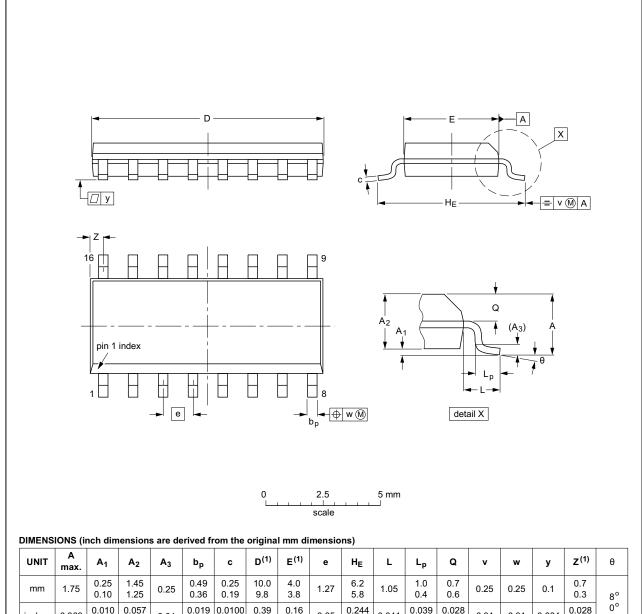
Fig 22. Package outline SOT38-4 (DIP16)

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8-channel analog multiplexer/demultiplexer

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	>	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

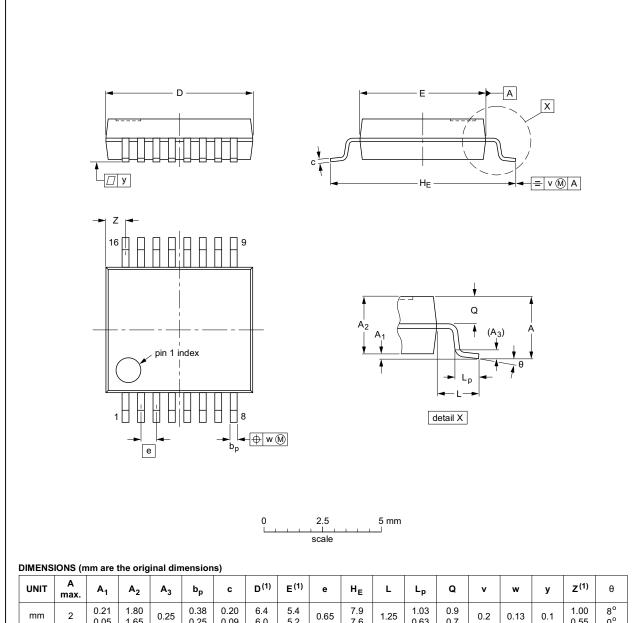
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IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
076E07	MS-012				99-12-27 03-02-19
		IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

Fig 23. Package outline SOT109-1 (SO16)

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

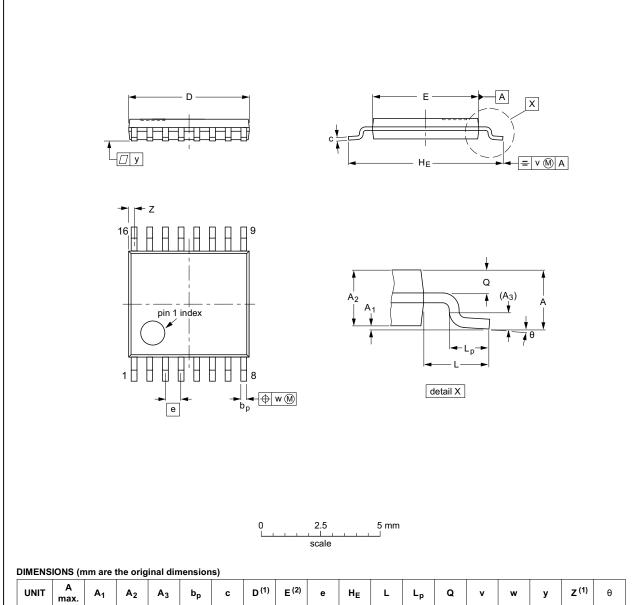
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE
SOT338-1		MO-150			99-12-27 03-02-19

Fig 24. Package outline SOT338-1 (SSOP16)

8-channel analog multiplexer/demultiplexer

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNI	Т	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mn	n	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT403-1		MO-153			-99-12-27 03-02-18

Fig 25. Package outline SOT403-1 (TSSOP16)

8-channel analog multiplexer/demultiplexer

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
DUT	Device Under Test

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4051B v.11	20140911	Product data sheet	-	HEF4051B v.10
Modifications:	• <u>Figure 20</u> : 7	est circuit modified		
HEF4051B v.10	20111117	Product data sheet	-	HEF4051B v.9
Modifications:	Legal pages	s updated.		
	 Changes in 	"General description", "Feat	tures and benefits" and	"Applications".
HEF4051B v.9	20100325	Product data sheet	-	HEF4051B v.8
HEF4051B v.8	20100301	Product data sheet	-	HEF4051B v.7
HEF4051B v.7	20091127	Product data sheet	-	HEF4051B v.6
HEF4051B v.6	20090924	Product data sheet	-	HEF4051B v.5
HEF4051B v.5	20090826	Product data sheet	-	HEF4051B v.4
HEF4051B v.4	20050112	Product data sheet	-	HEF4051B_CNV v.3
HEF4051B_CNV v.3	19950101	Product specification	-	HEF4051B_CNV v.2
HEF4051B_CNV v.2	19950101	Product specification	-	-

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15. Legal information

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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